TRA	NSMITTAL O	Docket No OKI.631					
In Re Application Of: Noriyuki MIURA							
	Serial No.	Filing Date	Examiner	Group Art Únit			
	NEW	DECEMBER 9, 2003	TO BE ASSIGNED	TO BE ASSIGNED			
Title: SOI TYPE MOSFET							
Address to: Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450							
	37 CFR 1.97(b)						
1. 🛚	The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application other than a continued prosecution application under 37 CFR 1.53(d); within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; before the mailing of a first Office Action on the merits, or before the mailing of a first Office Action after the filing of a request for continued examination under 37 CFR 1.114.						
	37 CFR 1.97(c)						
2.	The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of:						
	☐ the statement specified in 37 CFR 1.97(e);						
	OR						
	the fee set forth in 37 CFR 1.17(p).						

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li .	OSURE STATEMENT 7(c))	Docket No. OKI.631				
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Payment of Fee (Only complete if Applicant elects to pay the fee set forth in 37 CFR 1.17(p))						
The Director is hereby authorized to charge and credit Deposit Account No. as described below. Charge the amount of Credit any overpayment. Charge any additional fee required. Certificate of Transmission by Facsimile* Certificate of Mailing by First Class Mail Certify that this document and authorization to charge deposit account is being facsimile transmitted to the United States Patent and Trademark Office (F: Certify that this document and fee is being deposited on with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and is addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.						
(Date)						
	Signature	Signature of Person Mail	ing Correspondence			
Typed or Printed N	Name of Person Signing Certificate	Typed or Printed Name of Person	n Mailing Certificate			
*This certificate may only be used if paying by deposit account. Dated: DECEMBER 9, 2003 Signature ADAM C. VOLENTINE REG. NO. 33,289						
VOLENTINE FRANCOS 12200 SUNRISE VALLEY RESTON, VA 20191						
TEL. NO.: (703) 715-0870)					
cc:						

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Docket Number (Optional) Application Number OKI.631 **NEW** INFORMATION DISCLOSURE CITATION Applicant(s) Noriyuki MIURA (Use several sheets if necessary) Filing Date Group Art Unit December 9, 2003 To Be Assigned U.S. PATENT DOCUMENTS EXAMINER FILING DATE NAME SUBCLASS DATE CLASS REF DOCUMENT NUMBER INITIAL IF APPROPRIATE 6,093,592 07/25/2000 NAKABAYASHI et al. FOREIGN PATENT DOCUMENTS Translation REF DOCUMENT NUMBER DATE CLASS SUBCLASS COUNTRY YES Abstract 63-313865 12/21/1988 **JAPAN** В C 07-211902 08/11/1995 **JAPAN** Abstract 08-051198 02/20/1996 **JAPAN** D albatroet E 2001-135821 05/18/2001 **JAPAN** Abstract

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

Lisa T. Su et al., "OPTIMIZATION OF SERIES RESISTANCE IN SUB-0.2 μm SOI MOSFETs", 1993 IEEE, pgs. 723-726.

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Neal Kistler et al., "SCALING BEHAVIOR OF SUB-MICRON MOSFETs ON FULLY DEPLETED SOI", Solid-State Electronics Vol. 39, No. 4, 1996, pgs. 445-454.

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.